

CMOS Digital Integrated Circuits Silicon Monolithic

74HC540D,74HC541D

1. Functional Description

· Octal Bus Buffer

74HC540D: INVERTING, 3-STATE OUTPUTS 74HC541D: NON-INVERTING, 3-STATE OUTPUTS

2. General

The 74HC540D/74HC541D are high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C2MOS technology.

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The 74HC540D is an inverting type, and the 74HC541D is a non-inverting type.

When either $\overline{G}1$ or $\overline{G}2$ are high, the terminal outputs are in the high-impedance state.

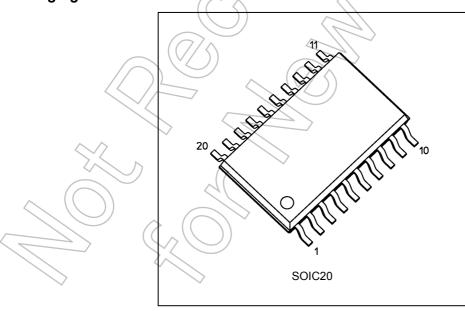
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

3. Features

- (1) Wide operating temperature range: $T_{opr} = -40$ to 125 °C (Note 1)
- (2) High speed: $t_{pd} = 10 \text{ ns (typ.)}$ at $V_{CC} = 6.0 \text{ V}$
- (3) Low power dissipation: $I_{CC} = 4.0 \mu A \text{ (max)}$ at $T_a = 25 \text{ °C}$
- (4) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (5) Wide operating voltage range: $V_{CC(opr)} = 2.0 \text{ V}$ to 6.0 V

Note 1: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

4. Packaging



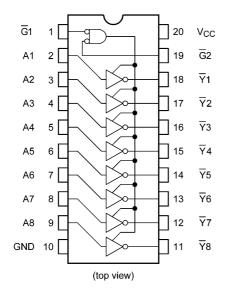
Start of commercial production

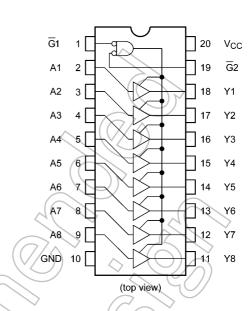


5. Pin Assignment

74HC540D



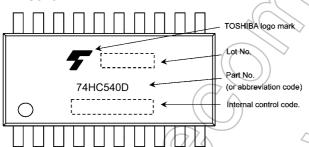


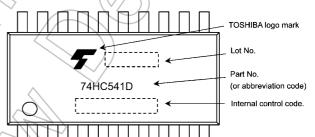


6. Marking

74HC540D



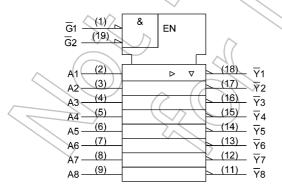




7. IEC Logic Symbol

74HC540D

74HC541D



$\frac{\overline{G}1}{\overline{G}2} \frac{(1)}{(19)}$	&	EN		
A1 (2) A2 (3) A3 (4) A4 (5) A5 (6) A6 (7) A7 (8) A8 (9)		D	▽	(18) Y1 (17) Y2 (16) Y3 (15) Y4 (14) Y5 (13) Y6 (12) Y7 (11) Y8



8. Truth Table

Input G1	Input G2	Input An	Output Yn	Output \overline{Y} n
Н	Х	Х	Z	Z
Х	Н	X	Z	Z
L	L	Н	Н	L
L	L	L	L	Н

X: Don't care
 Z: High impedance
 Yn: 74HC541D
 Yn: 74HC540D

9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V_{IN}		-0.5 to V _{CC} + 0.5	V
Output voltage	V _{OUT}		-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}		±20	mA
Output diode current	lok		±20	mA
Output current	I _{OUT} <		±35	mA
V _{CC} /ground current	Icc		±75	mA
Power dissipation	Pp	(Note 1)	500	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P_D derates linearly with -8 mW/°C above 85 °C

10. Operating Ranges (Note)

	7 7				
Characteristics	Symbol	Test Condition	Note	Rating	Unit
Supply voltage	V _{CC}			2.0 to 6.0	V
Input voltage	VIN			0 to V _{CC}	V
Output voltage	Vout			0 to V _{CC}	٧
Operating temperature	Topi		(Note 1)	-40 to 125	°C
Input rise and fall times	t_r, t_f	V _{CC} = 2.0 V		0 to 1000	ns
		V _{CC} = 4.5 V		0 to 500	
		V _{CC} = 6.0 V		0 to 400	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 1: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	_	V
				4.5	3.15	_	_	
				6.0	4.20	/	_	
Low-level input voltage	V _{IL}	_		2.0		7	0.50	V
				4.5			1.35	
				6.0	$(\langle // \rangle)$	_	1.80	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -20 μA	2.0	9.9	2.0	_	V
				4.5	4.4	4.5	_	
				6.0	5.9	6.0	_	
			$I_{OH} = -6 \text{ mA}$	4.5	4.18	4.31	_	
			$I_{OH} = -7.8 \text{ mA}$	6.0	5.68	5.80		
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 20 μA	2.0	_	0.0	0.1	V
				4.5	ϕ	0.0	0.1	
				6.0	-	0.0	// 0.1	
			$I_{OL} = 6 \text{ mA}$	4.5		0.17	0.26	
			$I_{OL} = 7.8 \text{ mA}$	6.0	5	0.18	0.26	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	77		±0.5	μА
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		6.0		_	±0.1	μА
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND	7//	6.0		_	4.0	μА

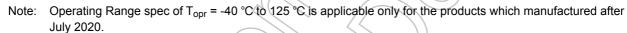
11.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}		(2)	2.0	1.50	_	V
		770		4.5	3.15	_	
				6.0	4.20	_	
Low-level input voltage) V _{IL}		3)	2.0	_	0.50	V
				4.5	_	1.35	
				6.0	_	1.80	
High-level output voltage	VoH	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	2.0	1.9	ı	V
				4.5	4.4	ı	
		$\langle \rangle$		6.0	5.9		
		9	I_{OH} = -6 mA	4.5	4.13	ı	
	/		$I_{OH} = -7.8 \text{ mA}$	6.0	5.63	ı	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I_{OL} = 20 μ A	2.0	_	0.1	V
	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\			4.5	_	0.1	
	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\			6.0	_	0.1	
			$I_{OL} = 6 \text{ mA}$	4.5	_	0.33	
			I _{OL} = 7.8 mA	6.0	_	0.33	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	_	±5.0	μА
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		6.0	_	40.0	μА



11.3. DC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition	l	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	V
				4.5	3.15		
				6.0	4.20		
Low-level input voltage	V _{IL}	_		2.0		0.50	V
				4.5		1.35	
				6.0		1.80	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	2.0	1.9		V
				4.5	<i>)</i> 4.4		
				6.0	5.9	ı	
			$I_{OH} = -6 \text{ mA}$	4.5	3.7		
			$I_{OH} = -7.8 \text{ mA}$	6.0	5.2	-	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 20 μA	2.0	- 7(0.1	V
				4.5	72	0.1	
				6.0	(\leftarrow)	0.1	
			$I_{OL} = 6 \text{ mA}$	4.5		0.4	
			$I_{OL} = 7.8 \text{ mA}$	6.0		0.4	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0		±5.0	μА
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND	>	6.0	<u></u>	±1.0	μА
Quiescent supply current	Icc	$V_{IN} = V_{CC}$ or GND		6.0) —	80.0	μА







11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	C _L (pF)	V _{CC} (V)	Min	Тур.	Max	Unit
Output transition time		t_{TLH}, t_{THL}			50	2.0	_	25	60	ns
						4.5	_	7	12	
						6.0		6	10	
Propagation delay time		t_{PLH}, t_{PHL}			50	2.0	Y	36	90	ns
						4.5	1	12	18	
						6.0))	10	15	
					150	(2.0/ <	\ _	51	130	
						4.5	/ —	17	26	
						6.0		14	22	
Output enable time		t_{PZL}, t_{PZH}		$R_L = 1 k\Omega$	50	2.0		45	125	ns
				. (4.5	_ /	14	25	
						6.0	1	12	21	
					150	2.0	X	6	165	
						4.5		19	33	
			/			6.0		16	28	
Output disable time		t_{PLZ}, t_{PHZ}		$R_L = 1 k\Omega$	50	2.0	Ń	4	125	ns
			40			(4.5		16	25	
				,		6.0		14	21	
Input capacitance		C _{IN}			((// \		5	10	pF
Output capacitance		C _{OUT}		· -/_			_	10	_	pF
Power dissipation	74HC540D	C _{PD}	(Note 1)	+/				32	_	pF
capacitance	74HC541D		$\langle \cdot \rangle$				_	35	_	

Note 1: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per bit)

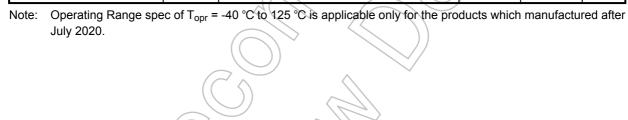
11.5. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition	C _L (pF)	V _{CC} (V)	Min	Max	Unit
Output transition time	t _{TLH} ,t _{THL}		50	2.0	_	75	ns
	\supset		>	4.5	_	15	
$\langle \rangle$				6.0	_	13	
Propagation delay time	t _{PLH} ,t _{PHL}		50	2.0	_	115	ns
	_	(4.5	_	23	
				6.0	_	20	
	• (150	2.0	_	165	
))		4.5	_	33	
				6.0	_	28	
Output enable time	t _{PZL} ,t _{PZH}	$R_L = 1 k\Omega$	50	2.0	_	155	ns
				4.5	_	31	
				6.0	_	26	
			150	2.0	_	205	
				4.5	_	41	
				6.0	_	35	
Output disable time	t_{PLZ}, t_{PHZ}	$R_L = 1 k\Omega$	50	2.0		155	ns
				4.5	_	31	
				6.0	_	26	
Input capacitance	C _{IN}	_			_	10	pF



11.6. AC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 6 ns)

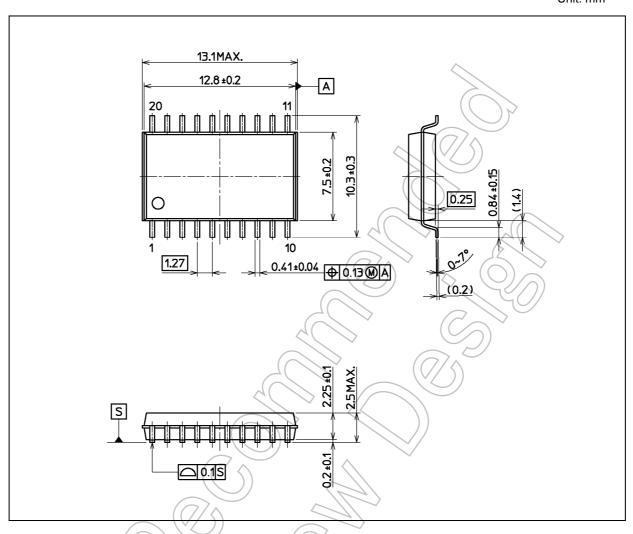
Characteristics	Symbol	Test Condition	C _L (pF)	V _{CC} (V)	Min	Max	Unit
Output transition time	t _{TLH} ,t _{THL}	_	50	2.0	_	85	ns
				4.5	_	17	
				6.0	//-	15	
Propagation delay time	t _{PLH} ,t _{PHL}	_	50	2.0		135	ns
				4.5		27	
				6.0) / /	24	
			150	2.0))-	190	
				4.5	_	38	
				(6.0)	_	32	
Output enable time	t_{PZL}, t_{PZH}	$R_L = 1 k\Omega$	50	2.0		175	ns
			4	4.5	- (35	
				6.0	\rightarrow	30]
			150	2.0	\bigcirc	235	
				4.5		47	
				6.0	17-20	40	
Output disable time	t_{PLZ}, t_{PHZ}	$R_L = 1 k\Omega$	50	2.0		175	ns
				4.5	$\langle j \rangle$	35	
				6.0		30	
Input capacitance	C _{IN}	7)	10	pF



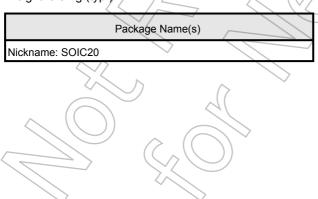


Package Dimensions

Unit: mm



Weight: 0.51 g (typ.)





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